Diode Semiconductor Device - Page 1 of 1

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**Inclosure Material:** Metal **Overall Length:** Between 0.060 inches and 0.064 inches **Terminal Length:** Between 0.060 inches and 0.064 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, dc and 60.0 breakdown voltage, dc **Voltage Tolerance In Percent:** -10.0/+10.0 **Current Rating Per Characteristic:** 10.00 nanoamperes forward current, average peak Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 solder stud Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0